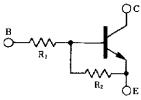


COMPOUND TRANSISTOR

on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

On-chip bias resistor
 (R₁ = 1.0 kΩ, R₂ = 10 kΩ)



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

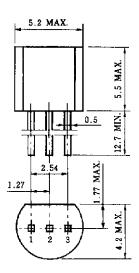
Complementary transistor with AN1A3Q

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	60	V
Collector to emitter voltage	VCEO	50	V
Emitter to base voltage	VEBO	5	V
Collector current (DC)	IC(DC)	100	mA
Collector current (Pulse)	IC(pulse) *	200	mA
Total power dissipation	Рт	250	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

* PW \leq 10 ms, duty cycle \leq 50 %

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Emitter EIAJ : SC-43B

2. Collector JEDEC : TO -92

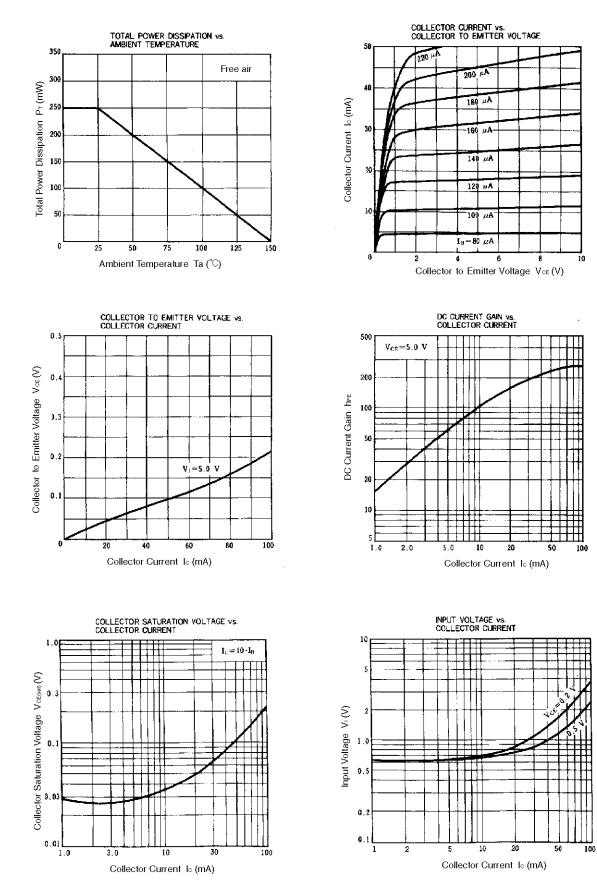
3. Base IEC PA33

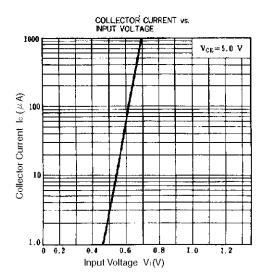
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0$			100	nA
DC current gain	hfe1 **	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 5.0 \text{ mA}$	35	60	100	-
DC current gain	hfe2 **	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 50 \text{ mA}$	80	230		-
Collector saturation voltage	VCE(sat) **	$I_{C} = 5.0 \text{ mA}, I_{B} = 0.25 \text{ mA}$		0.05	0.2	V
Low level input voltage	VIL **	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$		0.7	0.9	V
High level input voltage	VIH **	$V_{CE} = 0.2 V$, $I_C = 5.0 mA$	2.0	1.0		V
Input resistance	R1		0.7	1.0	1.3	kΩ
E-to-B resistance	R2		7	10	13	kΩ
Turn-on time	ton	$V_{\text{CC}} = 5 \text{ V}, \text{ R}_{\text{L}} = 1 \text{ k}\Omega$			0.2	μs
Storage time	tstg	$V_{I} = 5 V, PW = 2 \mu s$			5.0	μs
Turn-off time	toff	duty cycle≤2 %			6.0	μs

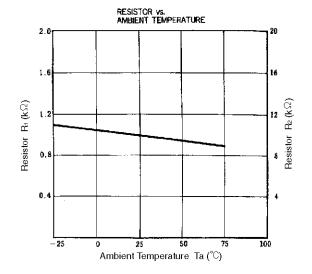
** PW \leq 350 μ s, duty cycle \leq 2 %

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TYPICAL CHARACTERISTICS (Ta = 25°C)







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